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With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



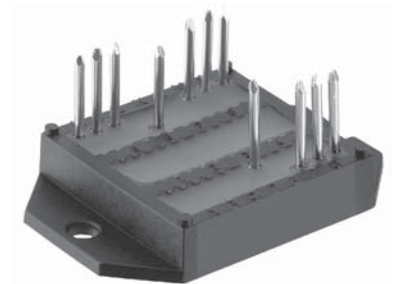
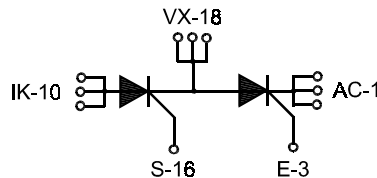
# Thyristor Modules

ECO-PAC 2

$I_{TRMS} = 2 \times 180A$   
 $I_{TAVM} = 2 \times 105A$   
 $V_{RRM} = 800-1800 V$

## Preliminary Data

$V_{RSM}$ $V_{DSM}$ V	$V_{RRM}$ $V_{DRM}$ V	Typ
900	800	VCC 105 - 08io7
1300	1200	VCC 105 - 12io7
1500	1400	VCC 105 - 14io7
1700	1600	VCC 105 - 16io7
1900	1800	VCC 105 - 18io7



Symbol	Conditions	Maximum Ratings		
$I_{TRMS}$		180	A	
$I_{TAVM}$	$T_C = 85^\circ C$ ; 180° sine	105	A	
$I_{TSM}$	$T_{VJ} = 45^\circ C$ ; $V_R = 0 V$ ; $t = 10 ms$ (50 Hz), sine	2250	A	
	$t = 8.3 ms$ (60 Hz), sine	2400	A	
	$T_{VJ} = 125^\circ C$ ; $V_R = 0 V$ ; $t = 10 ms$ (50 Hz), sine	2000	A	
	$t = 8.3 ms$ (60 Hz), sine	2150	A	
$I^2dt$	$T_{VJ} = 45^\circ C$ ; $V_R = 0 V$ ; $t = 10 ms$ (50 Hz), sine	25300	A <sup>2</sup> s	
	$t = 8.3 ms$ (60 Hz), sine	23900	A <sup>2</sup> s	
	$T_{VJ} = 125^\circ C$ ; $V_R = 0 V$ ; $t = 10 ms$ (50 Hz), sine	20000	A <sup>2</sup> s	
	$t = 8.3 ms$ (60 Hz), sine	19100	A <sup>2</sup> s	
$(di/dt)_{cr}$	$T_{VJ} = 125^\circ C$ ; $f = 50 Hz$ ; $t_p = 200 \mu s$ ; $V_D = \frac{2}{3}V_{DRM}$ ; $I_G = 0.45 A$	repetitive, $I_T = 250 A$	150	A/ $\mu s$
		non repetitive, $I_T = I_{TAVM}$	500	A/ $\mu s$
$(dv/dt)_{cr}$	$T_{VJ} = 125^\circ C$ ; $V_{DR} = \frac{2}{3}V_{DRM}$ $R_{GK} = \infty$ , method 1 (linear voltage rise)		1000	V/ $\mu s$
$P_{GM}$	$T_{VJ} = 125^\circ C$ ;	$t_p = 30 ms$	$\leq 10$	W
	$I_T = I_{TAVM}$ ;	$t_p = 300 ms$	$\leq 5$	W
$P_{GAVM}$			0.5	W
$V_{RGM}$			10	V
$T_{VJ}$			-40 ... + 125	°C
$T_{VJM}$			125	°C
$T_{stg}$			-40 ... + 125	°C
$V_{ISOL}$	50/60 Hz, RMS	$t = 1 min$	3000	V ~
	$I_{ISOL} \leq 1 mA$	$t = 1 s$	3600	V ~
$M_d$	Mounting torque (M4)		1.5 - 2.0	Nm
			14 - 18	lb.in.
Weight	typ.		26	g

### Features

- Isolation voltage 3600 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

### Applications

- DC motor control
- Light and temperature control
- Softstart AC motor controller
- Solid state switches

### Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling
- High power density
- Small and light weight

Data according to IEC 60747 refer to a single thyristor unless otherwise stated

IXYS reserves the right to change limits, test conditions and dimensions.

Component		Characteristic Values		
Symbol	Conditions	min.	typ.	max.
$I_D, I_R$	$T_{VJ} = 125^\circ\text{C}; V_R = V_{RRM}; V_D = V_{DRM}$			5 mA
$V_T$	$I_T = 300\text{ A}; T_{VJ} = 25^\circ\text{C}$			1.5 V
$V_{TO}$	For power-loss calculations only			0.8 V
$r_T$				2.4 mΩ
$V_{GT}$	$V_D = 6\text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$			1.5 V 1.6 V
$I_{GT}$	$V_D = 6\text{ V}; T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = -40^\circ\text{C}$			150 mA 200 mA
$V_{GD}$	$T_{VJ} = 125^\circ\text{C}; V_D = \frac{2}{3}V_{DRM}$			0.2 V
$I_{GD}$	$T_{VJ} = 125^\circ\text{C}; V_D = \frac{2}{3}V_{DRM}$			10 mA
$I_L$	$T_{VJ} = 25^\circ\text{C}; t_p = 10\text{ ms}$ $I_G = 0.45\text{ A}; di_G/dt = 0.45\text{ A}/\mu\text{s}$			450 mA
$I_H$	$T_{VJ} = 25^\circ\text{C}; V_D = 6\text{ V}; R_{GK} = \infty$			200 mA
$t_{gd}$	$T_{VJ} = 25^\circ\text{C}; V_D = \frac{1}{2}V_{DRM}$ $I_G = 0.45\text{ A}; di_G/dt = 0.45\text{ A}/\mu\text{s}$			2 μs
$R_{thJC}$	per Thyristor; DC per module			0.26 K/W 0.13 K/W
$R_{thCH}$	per Thyristor; DC per module		0,2 0,1	K/W K/W
$d_s$	Creeping distance on surface			11.2 mm
$d_A$	Creeping distance in air			5.0 mm
$a$	Max. allowable acceleration			50 m/s <sup>2</sup>

